

Datasheet

V2019.1.0

G3S06505H

650V/ 5A Silicon Carbide Power Schottky Barrier Diode

Features

- Rated to 650V at 5 Amps
- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behaviour
- High temperature operation
- High frequency operation

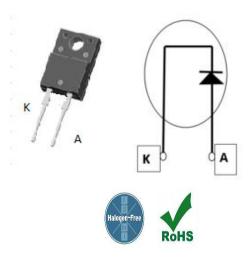
Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements

Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV

Key Characteristics			
V _{RRM}	650	V	
I _F , T _c =140℃	5	Α	
Qc	23	nC	



Part No.	Package Type	Marking
G3S06505H	TO-220F	G3S06505H

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}		650	V
Surge Peak Reverse Voltage	V _{RSM}		650	
DC Blocking Voltage	V _{DC}		650	
Continuous Forward Current	l _F	T _c =25°C T _c =135°C T _c =140°C	15.4 10.4 5	A
Repetitive Peak Forward Surge Current	I _{FRM}	$T_c=25^{\circ}C$, tp=10ms, Half Sine Wave	25	А
Non-repetitive Peak Forward Surge Current	I _{FSM}	T _c =25°C, tp=10ms, Half Sine Wave	78	А
Power Dissipation	P _{TOT}	T _c =25°C T _c =110°C	46 20	W W
Operating Junction	Tj		-55°C to 175°C	°C
Storage Temperature	T _{stg}		-55°C to 175°C	°C
Mounting Torque		M3 Screw 6-32 Screw	1 8.8	Nm lbf-in

Thermal Characteristics

Deremeter	Sumbol	Test Condition	Value	Unit
Parameter	arameter Symbol		Тур.	Unit
Thermal resistance from junction to case	R_{thJC}		3.25	°C/W

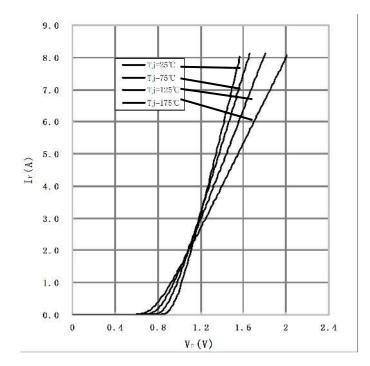
Devementer	Symbol	Test Conditions	Numerical		Unit
Parameter	Symbol	Test conditions	Тур.	Max.	Unit
	VF	Ι _F =5Α, Τ _j =25°C	1.32	1.7	N/
Forward Voltage		I _F =5A, T _j =175°C	1.55	2.5	V
Deverse Current	I _R	V _R =650V, T _j =25°C	10	50	۵
Reverse Current		V _R =650V, T _j =175°C	20	100	μA
		V _R =400V, T _j =150°C			
Total Capacitive Charge	Q _c	$Qc = \int_0^{VR} C(V)dV$	23	-	nC
		V _R =0V, T _j =25°C, f=1MHZ	424	434	
Total Capacitance	C	V _R =200V, T _j =25°C, f=1MHZ	44	45	рF
		V _R =400V, T _j =25°C, f=1MHZ	42.5	43	

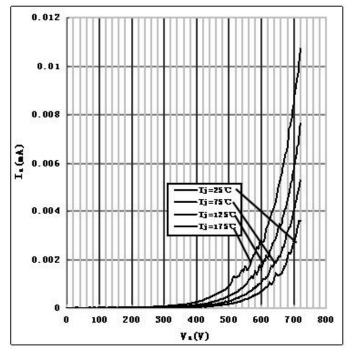
Electrical Characteristics

Performance Graphs

1) Forward IV characteristics as a function of Tj :

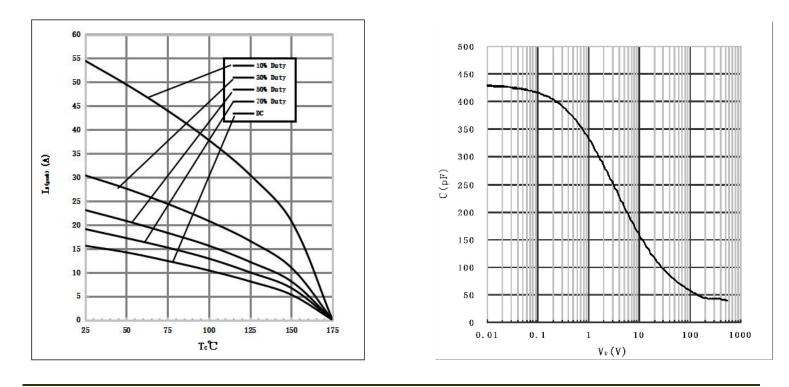
2) Reverse IV characteristics as a function of Tj :



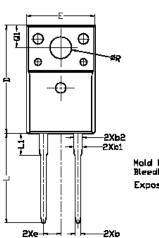


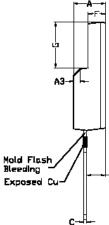
3) Current Derating

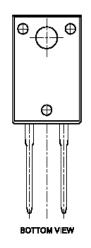
4)Capacitance vs. reverse voltage :



Package TO-220F







	DIMENSIONS			
SYMBOL	Mn,	Nom,	Max,	
А	4,60	4,70	4,80	
b	0,70	0,80	0,91	
b1	1,20	1,30	1,47	
b2	1,10	1,20	1,30	
с	0.45	0.50	0.63	
D	15,80	15.87	15.97	
е	2.54			
Е	10.00	10.10	10.30	
F	2,44	2,54	2,64	
G	6,50	6,70	6,90	
L	12,90	13,10	13,30	
L1	3,13	3,23	3,33	
a	2.65	2.75	2,85	
Q1	3.20	3.30	3,40	
ΦR	3.08	3.18	3,28	

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: <u>http://globalpowertech.cn/English/index.asp</u>

More product datasheets and company information can be found in: <u>http://globalpowertech.cn/English/index.asp</u>

